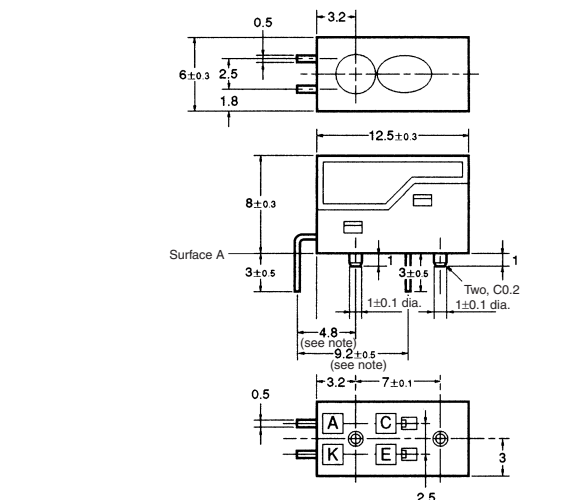


Photomicrosensor (Reflective)

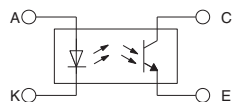
EE-SY169A

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



Internal Circuit



Note: These dimensions are for the surface A. Other lead wire pitch dimensions are for the housing surface.

Unless otherwise specified, the tolerances are as shown below.

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

■ Features

- High-quality model with plastic lenses.
- Highly precise sensing range with a tolerance of ±0.6 mm horizontally and vertically.
- Convergent reflective model with infrared LED.
- RoHS Compliant.

■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rated value
Emitter	Forward current	I_F	50 mA (see note 1)
	Pulse forward current	I_{FP}	1 A (see note 2)
	Reverse voltage	V_R	3 V
Detector	Collector–Emitter voltage	V_{CEO}	30 V
	Emitter–Collector voltage	V_{ECO}	---
	Collector current	I_C	20 mA
	Collector dissipation	P_C	100 mW (see note 1)
	Ambient temperature	T_{opr}	0°C to 70°C
Storage	Operating	T_{opr}	0°C to 70°C
	Storage	T_{stg}	–20°C to 80°C
Soldering temperature		T_{sol}	260°C (see note 3)

Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

2. The pulse width is 10 μs maximum with a frequency of 100 Hz.

3. Complete soldering within 10 seconds.

■ Ordering Information

Description	Model
Photomicrosensor (reflective)	EE-SY169A

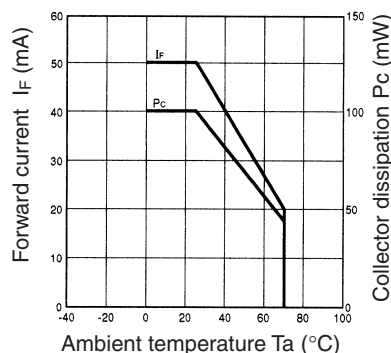
■ Electrical and Optical Characteristics (Ta = 25°C)

Item		Symbol	Value	Condition
Emitter	Forward voltage	V_F	1.5 V max.	$I_F = 30$ mA
	Reverse current	I_R	10 μA max.	$V_R = 4$ V
	Peak emission wavelength	λ_P	920 nm typ.	$I_F = 20$ mA
Detector	Light current	I_L	160 μA min., 2,000 μA max.	$I_F = 20$ mA, $V_{CE} = 5$ V White paper with a reflection ratio of 90%, $d = 4$ mm (see note)
	Dark current	I_D	2 nA typ., 200 nA max.	$V_{CE} = 5$ V, 0 lx
	Leakage current	I_{LEAK}	2 μA max.	$I_F = 20$ mA, $V_{CE} = 5$ V with no reflection
	Collector–Emitter saturated voltage	$V_{CE(sat)}$	---	---
	Peak spectral sensitivity wavelength	λ_P	850 nm typ.	$V_{CE} = 5$ V
Rising time		t_r	30 μs typ.	$V_{CC} = 5$ V, $R_L = 1$ kΩ, $I_L = 1$ mA
Falling time		t_f	30 μs typ.	$V_{CC} = 5$ V, $R_L = 1$ kΩ, $I_L = 1$ mA

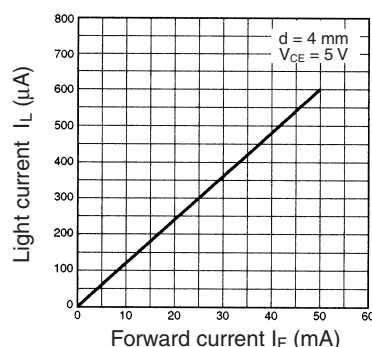
Note: The letter “d” indicates the distance between the top surface of the sensor and the sensing object.

Engineering Data

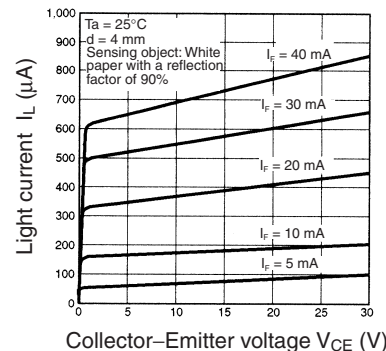
Forward Current vs. Collector Dissipation Temperature Rating



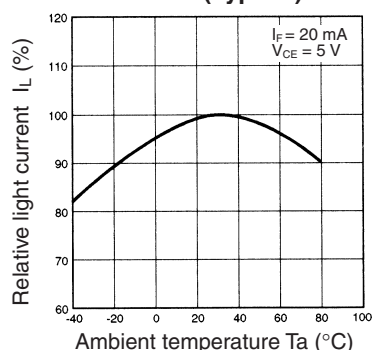
Light Current vs. Forward Current Characteristics (Typical)



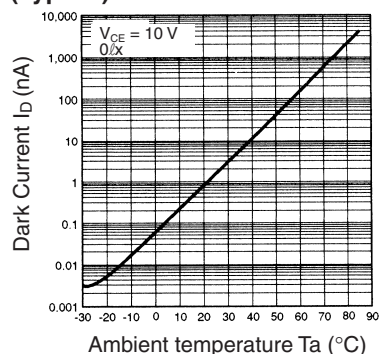
Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



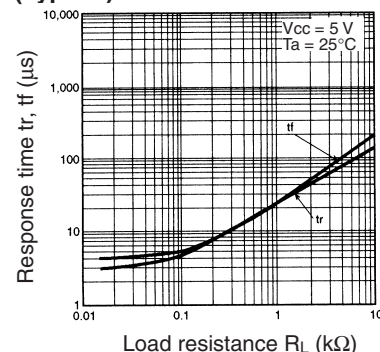
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



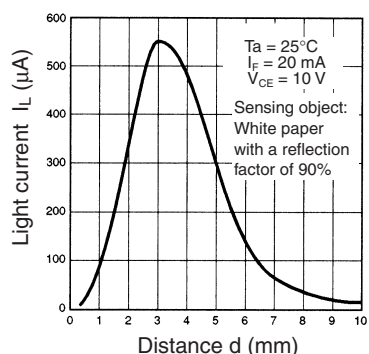
Dark Current vs. Ambient Temperature Characteristics (Typical)



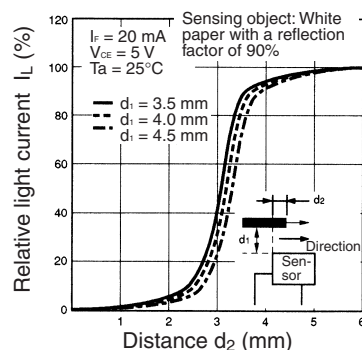
Response Time vs. Load Resistance Characteristics (Typical)



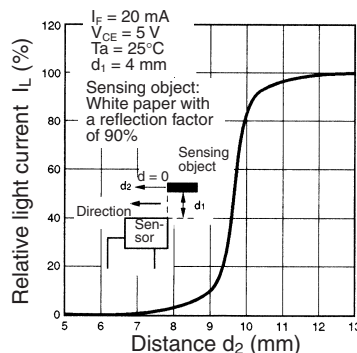
Sensing Distance Characteristics (Typical)



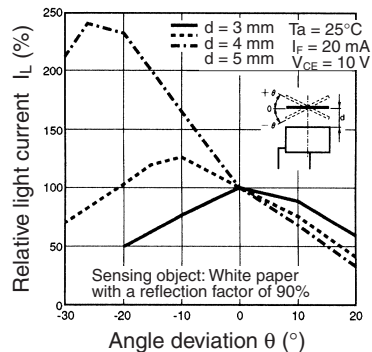
Sensing Position Characteristics (Typical)



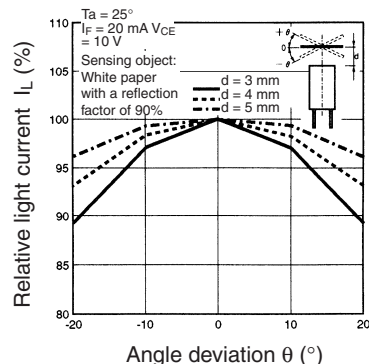
Sensing Position Characteristics (Typical)



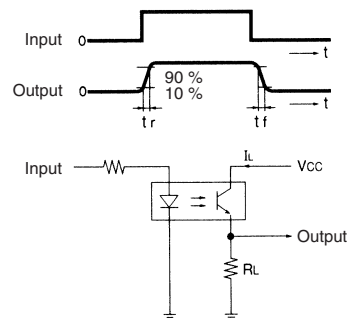
Sensing Angle Characteristics (Typical)

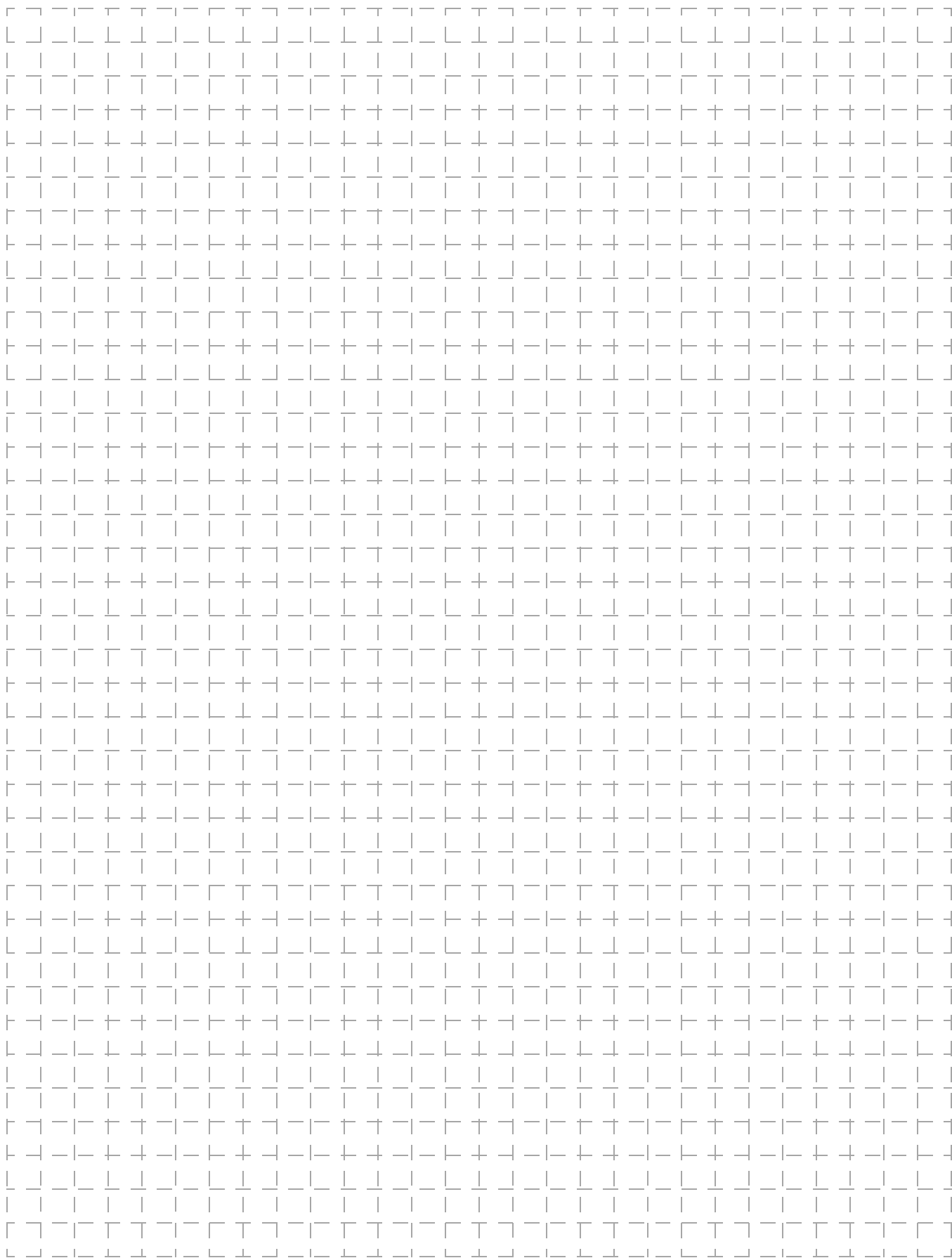


Sensing Angle Characteristics (Typical)



Response Time Measurement Circuit





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ALL DIMENSIONS SHOWN ARE IN MILLIMETERS.

To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

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